

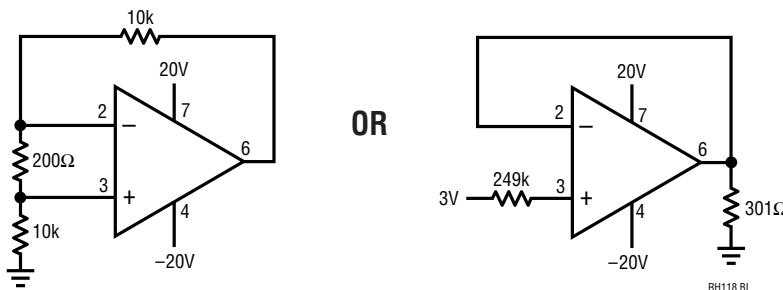
## DESCRIPTION

The RH118 is a precision, high speed operational amplifier which offers wide bandwidth and high slew rate. Unlike many wideband amplifiers, the RH118 is unity-gain stable and has a slew rate of 50V/ $\mu$ s.

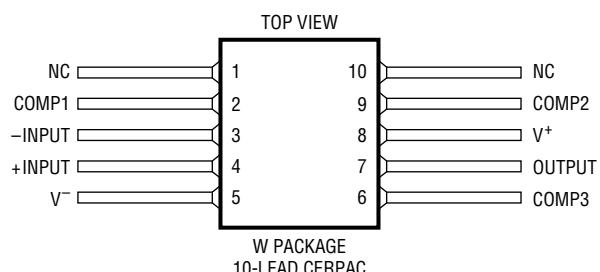
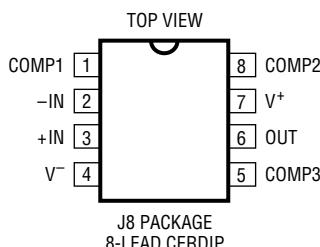
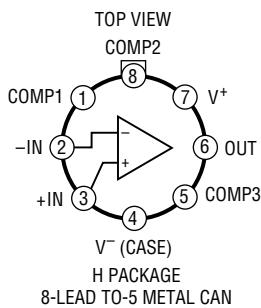
The wafer lots are processed to Linear Technology's in-house Class S flow to yield circuits usable in stringent military applications.

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## BURN-IN CIRCUIT (Each Amplifier)



## PACKAGE/ORDER INFORMATION



**TABLE 1: ELECTRICAL CHARACTERISTICS** (Preirradiation) (Note 3)

SYMBOL	PARAMETER	CONDITIONS	NOTES	T <sub>A</sub> = 25°C			SUB-GROUP	−55°C ≤ T <sub>A</sub> ≤ 125°C			SUB-GROUP	UNITS
				MIN	TYP	MAX		MIN	TYP	MAX		
V <sub>OS</sub>	Input Offset Voltage				4	1			6		2,3	mV
I <sub>OS</sub>	Input Offset Current				50	1			100		2,3	nA
I <sub>B</sub>	Input Bias Current				250	1			500		2,3	nA
R <sub>IN</sub>	Input Resistance		4	1								MΩ
A <sub>V</sub>	Large-Signal Voltage Gain	V <sub>S</sub> = ±15V, V <sub>OUT</sub> = ±10V R <sub>L</sub> ≥ 2k		50			1	25			2,3	V/mV
SR	Slew Rate	V <sub>S</sub> = ±15V, A <sub>V</sub> = 1	5	50								V/μs
GBW	Gain Bandwidth Product	V <sub>S</sub> = ±15V			15							MHz
	Output Voltage Swing	V <sub>S</sub> = ±15V, R <sub>L</sub> = 2k		±12			4	±12			5,6	V
	Input Voltage Range	V <sub>S</sub> = ±20V		±16.5			1	±16.5			2,3	V
I <sub>S</sub>	Supply Current				8	1						mA
		T <sub>A</sub> = 125°C							7		2	mA
CMRR	Common Mode Rejection Ratio			80			1	80			2,3	dB
PSRR	Power Supply Rejection Ratio			70			1	70			2,3	dB

**TABLE 1A: ELECTRICAL CHARACTERISTICS** (Postirradiation) (Note 6)

SYMBOL	PARAMETER	CONDITIONS	NOTES	10Krad(Si)		20Krad(Si)		50Krad(Si)		100Krad(Si)		200Krad(Si)		UNITS
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
V <sub>OS</sub>	Input Offset Voltage				4		4		4		4		10	mV
I <sub>OS</sub>	Input Offset Current				50		50		50		50		100	nA
I <sub>B</sub>	Input Bias Current				250		250		250		300		400	nA
R <sub>IN</sub>	Input Resistance		4	1		1		1		0.5		0.5		MΩ
A <sub>V</sub>	Large-Signal Voltage Gain	V <sub>S</sub> = ±15V, V <sub>OUT</sub> = ±10V R <sub>L</sub> ≥ 2k		50		50		50		50		25		V/mV
SR	Slew Rate	V <sub>S</sub> = ±15V, A <sub>V</sub> = 1	5	50		50		50		50		50		V/μs
GBW	Gain Bandwidth Product	V <sub>S</sub> = ±15V			15(Typ)		15(Typ)		15(Typ)		15(Typ)		15(Typ)	MHz
	Output Voltage Swing	V <sub>S</sub> = ±15V, R <sub>L</sub> = 2k		±12		±12		±12		±12		±12		V
	Input Voltage Range			±16.5		±16.5		±16.5		±15		±12		V
I <sub>S</sub>	Supply Current				8		8		8		8		8	mA
CMRR	Common Mode Rejection Ratio			80		80		80		80		70		dB
PSRR	Power Supply Rejection Ratio			70		70		70		70		60		dB

## ELECTRICAL CHARACTERISTICS (Continued)

**Note 1:** The inputs are shunted with back-to-back Zeners for overvoltage protection. Excessive current will flow if a differential voltage greater than 5V is applied to the inputs.

**Note 2:** For supply voltages less than  $\pm 15V$ , the maximum input voltage is equal to the supply voltage.

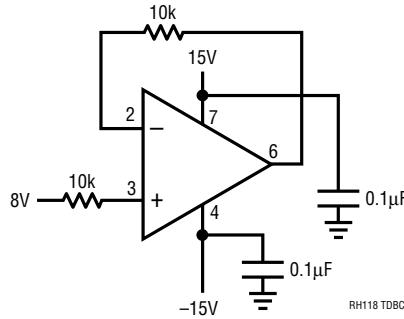
**Note 3:** These specifications apply for  $\pm 5V \leq V_S \leq \pm 20V$ . The power supplies must be bypassed with a  $0.1\mu F$  or greater disc capacitor within four inches of the device.

**Note 4:** Guaranteed by design, characterization or correlation to other tested parameters.

**Note 5:** Slew rate is 100% tested at wafer probe testing. It is QA sample tested in finished package form.

**Note 6:**  $T_A = 25^\circ C$ ,  $V_S = \pm 20V$ ,  $V_{CM} = 0V$ , unless otherwise specified. Supply bypassed per Note 3.

## TOTAL DOSE BIAS CIRCUIT



## TABLE 2: ELECTRICAL TEST REQUIREMENTS

MIL-STD-883 TEST REQUIREMENTS	SUBGROUP
Final Electrical Test Requirements (Method 5004)	1*,2,3,4,5,6
Group A Test Requirements (Method 5005)	1,2,3,4,5,6
Group B and D End Point Electrical Parameters (Method 5005)	1,2,3

\* PDA Applies to subgroup 1. See PDA Test Notes.

### PDA Test Notes

The PDA is specified as 5% based on failures from group A, subgroup 1, tests after cooldown as the final electrical test in accordance with method 5004 of MIL-STD-883 Class B. The verified failures (including Delta parameters) of group A, subgroup 1, after burn-in divided by the total number of devices submitted for burn-in in that lot shall be used to determine the percent for the lot.

Linear Technology Corporation reserves the right to test to tighter limits than those given.

## TYPICAL PERFORMANCE CHARACTERISTICS

